U.S. Department of Commerce, Patent and Trademark	Atty. Docket No.		Application No.
INFORMATION DISCLOSURE STATEMENT BY APPLICANT	SNDK.A06US5		09/759,119
	Applicant(s)		Conf. No.
(Use several sheets if necessary)	Harari et al.		1201
(Form PTO-1449)	Filing Date		Group
	January 11, 2001		2827

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TN	6	4,279,024	7/14/81	Schenk			
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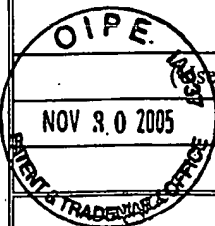|		Document	Date	Country	Class	Subclass	Translation Yes	No

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TN		Office Action for Application No. 09/606,911 mailed November 9, 2005, 15 pages.

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Foreign Patent Documents

							Translation	
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